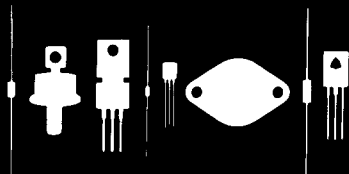


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145 Adams Avenue
Hauppauge, New York 11788



2N3442

Single Diffused (Hometaxial)
NPN Silicon Power Transistor

JEDEC TO 3 CASE

DESCRIPTION

The CENTRAL SEMICONDUCTOR 2N3442 is a Silicon NPN Single Diffused (Hometaxial) High Voltage Power Transistor designed for high voltage, high power amplifier applications.

MAXIMUM RATINGS ($T_C=25^{\circ}\text{C}$)

	SYMBOL		UNIT
Collector-Base Voltage	V_{CB0}	160	V
Collector-Emitter Voltage	V_{CEV}	160	V
Collector-Emitter Voltage	V_{CEO}	140	V
Emitter-Base Voltage	V_{EBO}	7.0	V
Collector Current	I_C	10	A
Collector Current (PEAK)	I_{CM}	15	A
Base Current	I_B	7.0	A
Power Dissipation	P_D	117	W
Operating and Storage			
Junction Temperature	T_J, T_{stg}	-65 TO +200	$^{\circ}\text{C}$
Thermal Resistance	θ_{JC}	1.5	$^{\circ}\text{C/W}$

ELECTRICAL CHARACTERISTICS ($T_C=25^{\circ}\text{C}$)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNIT
I_{CEV}	$V_{CE}=140\text{V}, V_{BE}=1.5\text{V}$		5.0	mA
I_{CEO}	$V_{CE}=140\text{V}$		200	mA
I_{EBO}	$V_{BE}=7.0\text{V}$		5.0	mA
BV_{CEO}	$I_C=0.2\text{A}$	140		V
$V_{CE(SAT)}$	$I_C=10\text{A}, I_B=2.0\text{A}$		5.0	V
$V_{BE(ON)}$	$V_{CE}=4.0\text{V}, I_C=10\text{A}$		5.7	V
h_{FE}	$V_{CE}=4.0\text{V}, I_C=3.0\text{A}$	20	70	
h_{FE}	$V_{CE}=4.0\text{V}, I_C=10\text{A}$	7.5		
h_{fe}	$V_{CE}=4.0\text{V}, I_C=2.0\text{A}, f=1.0\text{kHz}$	12	72	
f_T	$V_{CE}=4.0\text{V}, I_C=2.0\text{A}, f=40\text{kHz}$	80		kHz

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities
- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

1. If requesting Tin/Lead plated devices, add the suffix " TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
2. If requesting Lead (Pb) Free plated devices, add the suffix " PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

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